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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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H7N0203AB

Silicon N Channel MOS FET High Speed Power Switching

REJ03G1119-0500

(Previous: ADE-208-1490C)

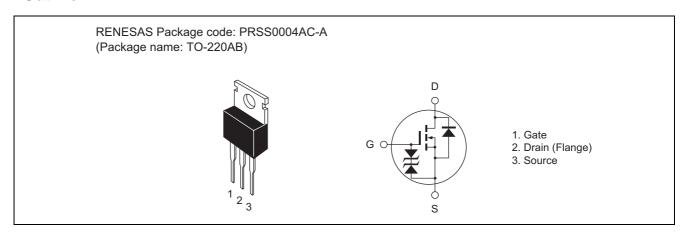
Rev.5.00

Sep 07, 2005

Features

- Low on-resistance $R_{DS \; (on)} = 2.4 \; m\Omega \; typ. \label{eq:resistance}$
- Low drive current
- 4.5 V gate drive device can be driven from 5 V source

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V_{DSS}	20	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	90	A
Drain peak current	I _{D (pulse)} Note 1	360	A
Body-drain diode reverse drain current	I_{DR}	90	A
Avalanche current	I _{AP} Note 2	20	A
Avalanche energy	E _{AR} Note 2	40	mJ
Channel dissipation	Pch Note 3	100	W
Channel to case thermal impedance	θ ch-c	1.25	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tch = 25°C, Rg \geq 50 Ω

3. Value at Tc = 25°C

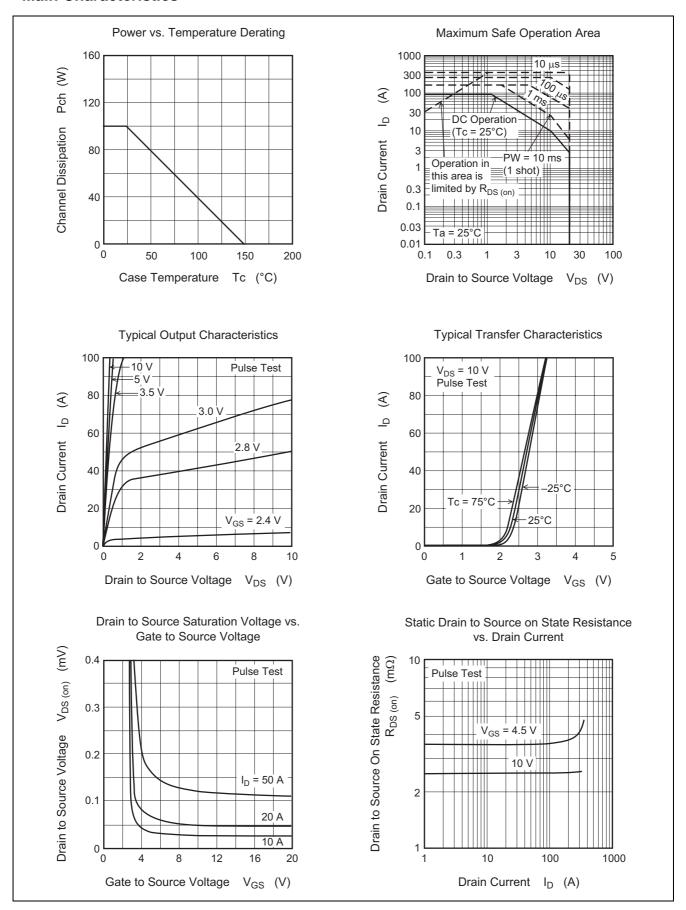
Electrical Characteristics

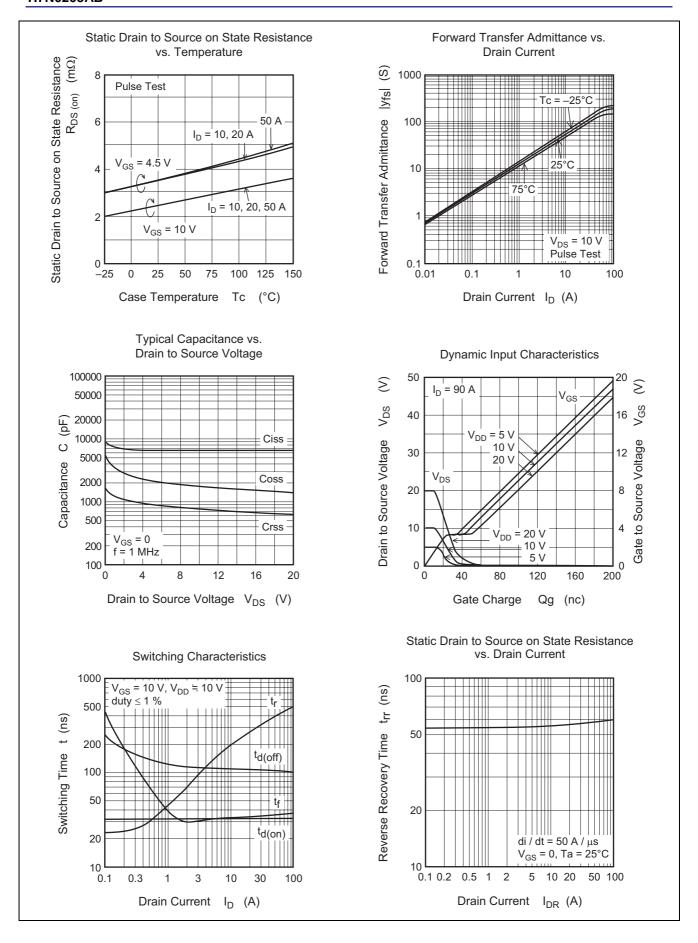
 $(Ta = 25^{\circ}C)$

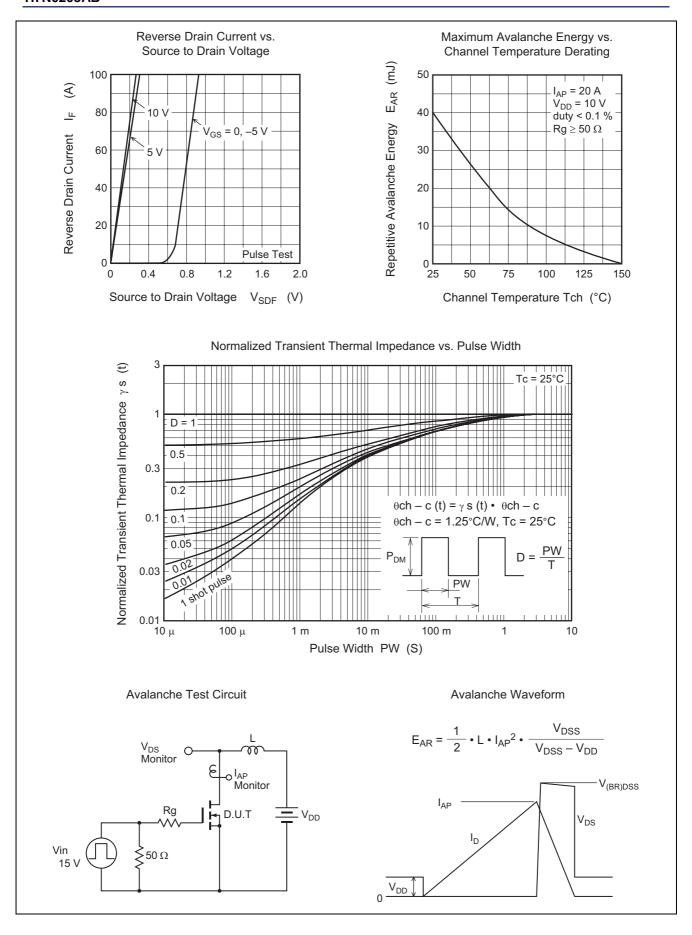
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	20	_		>	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _(BR) GSS	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}		_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μΑ	$V_{DS} = 20 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	1.0	_	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Static drain to source on state resistance	R _{DS (on)}	_	2.4	3.0	mΩ	$I_D = 45 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note 4}}$
		_	3.5	5.1	mΩ	$I_D = 45 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y _{fs}	80	140	_	S	$I_D = 45 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	6800	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	1850	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	750	_	pF	f = 1 MHz
Total gate charge	Qg	_	110	_	nC	V _{DD} = 10 V
Gate to source charge	Qgs	_	22	_	nC	V _{GS} = 10 V
Gate to drain charge	Qgd	_	20	_	nC	I _D = 90 A
Turn-on delay time	t _{d (on)}	_	32	_	ns	$V_{GS} = 10 \text{ V}, I_D = 45 \text{ A}$
Rise time	t _r	_	380	_	ns	$R_L = 0.22 \Omega$
Turn-off delay time	t _{d (off)}	_	110	_	ns	$Rg = 4.7 \Omega$
Fall time	t _f	_	35	_	ns	
Body-drain diode forward voltage	V_{DF}	_	0.90	_	V	I _F = 90 A, V _{GS} = 0
Body-drain diode reverse recovery time	t _{rr}	_	60	_	ns	$I_F = 90 \text{ A}, V_{GS} = 0$
						di _F /dt = 50 A/μs

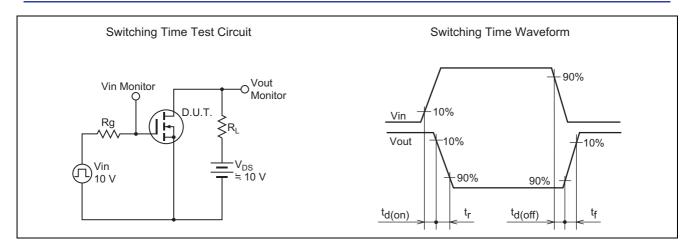
Note: 4. Pulse test

Main Characteristics

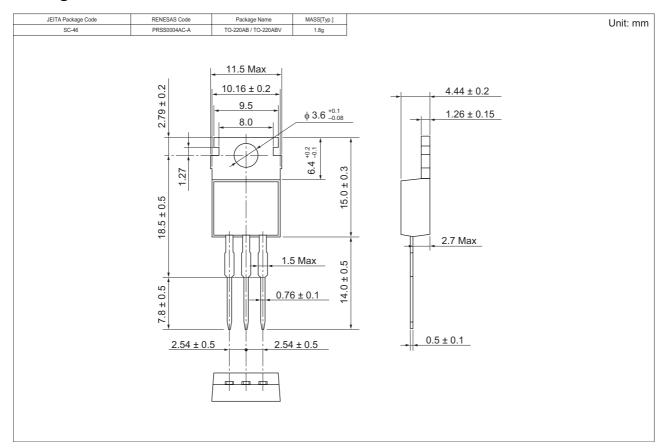








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
H7N0203AB-E	500 pcs	Box (Sack)

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